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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR NP50P06KDG

SWITCHING **P-CHANNEL POWER MOSFET**

DESCRIPTION

The NP50P06KDG is P-channel MOS Field Effect Transistor designed for high current switching applications.

<R> **ORDERING INFORMATION**

PART NUMBER	LEAD PLATING	PACKING	PACKAGE		
NP50P06KDG-E1-AY Note					
NP50P06KDG-E2-AY Note	Pure Sn (Tin)	Tape 800 p/reel	TO-263 (MP-25ZK)		

Note Pb-free (This product does not contain Pb in external electrode.)

FEATURES

Super low on-state resistance

 $R_{DS(on)1} = 17 \text{ m}\Omega \text{ MAX.}$ (Vgs = -10 V, ID = -25 A)

 $R_{DS(on)2} = 23 \text{ m}\Omega \text{ MAX.}$ (Vgs = -4.5 V, ID = -25 A)

- Low input capacitance
- Ciss = 5000 pF TYP.

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}C$)

Drain to Source Voltage (V _{GS} = 0 V)	VDSS	-60	V
Gate to Source Voltage (VDs = 0 V)	Vgss	∓20	V
Drain Current (DC) (Tc = 25°C)	D(DC)	∓50	А
Drain Current (pulse) ^{Note1}	D(pulse)	∓150	А
Total Power Dissipation (Tc = 25° C)	Ρτ1	90	W
Total Power Dissipation (T _A = 25°C)	Pt2	1.8	W
Channel Temperature	Tch	175	°C
Storage Temperature	Tstg	-55 to +175	°C
Single Avalanche Current Note2	las	32	Α
Single Avalanche Energy ^{Note2}	Eas	106	mJ

Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

2. Starting T_{ch} = 25°C, V_{DD} = -30 V, R_G = 25 Ω , V_{GS} = $-20 \rightarrow 0$ V

THERMAL RESISTANCE

Channel to Case Thermal Resistance	Rth(ch-C)	1.67	°C/W
Channel to Ambient Thermal Resistance	Rth(ch-A)	83.3	°C/W

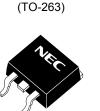
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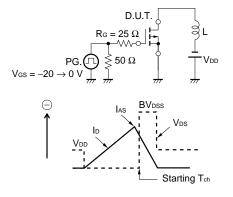
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	loss	V _{DS} = -60 V, V _{GS} = 0 V			-10	μA
Gate Leakage Current	Igss	V _{GS} = ∓20 V, V _{DS} = 0 V			∓100	nA
Gate to Source Threshold Voltage	V _{GS(th)}	V_{DS} = -10 V, I_{D} = -1 mA	-1.0	-1.6	-2.5	V
Forward Transfer Admittance Note	y _{fs}	V _{DS} = -10 V, I _D = -25 A	15	30		S
Drain to Source On-state Resistance Note	RDS(on)1	V _{GS} = -10 V, I _D = -25 A		13.5	17	mΩ
	RDS(on)2	V _{GS} = -4.5 V, I _D = -25 A		15.4	23	mΩ
Input Capacitance	Ciss	V _{DS} = -10 V,		5000		pF
Output Capacitance	Coss	V _{GS} = 0 V,		600		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		300		pF
Turn-on Delay Time	t _{d(on)}	V_{DD} = -30 V, I _D = -25 A,		20		ns
Rise Time	tr	V _{GS} = -10 V,		45		ns
Turn-off Delay Time	t _{d(off)}	R _G = 0 Ω		405		ns
Fall Time	tr			270		ns
Total Gate Charge	QG	V _{DD} = -48 V,		95		nC
Gate to Source Charge	Q _{GS}	V _{GS} = -10 V,		10		nC
Gate to Drain Charge	Qgd	I _D = -50 A		26		nC
Body Diode Forward Voltage Note	V _{F(S-D)}	IF = -50 A, VGS = 0 V		0.97	1.5	V
Reverse Recovery Time	trr	IF = -50 A, VGS = 0 V,		50		ns
Reverse Recovery Charge	Qrr	di/dt = −100 A/ <i>μ</i> s		70		nC

ELECTRICAL CHARACTERISTICS (TA = 25°C)

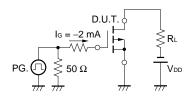
Note Pulsed test PW \leq 350 μ s, Duty Cycle \leq 2%

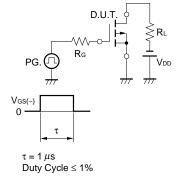
TEST CIRCUIT 1 AVALANCHE CAPABILITY

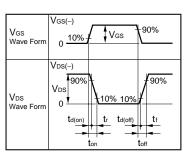
TEST CIRCUIT 2 SWITCHING TIME



TEST CIRCUIT 3 GATE CHARGE







TOTAL POWER DISSIPATION vs.

75 100 125 150 175 200

Tc - Case Temperature - °C

CASE TEMPERATURE

120

100

80

60

40

20

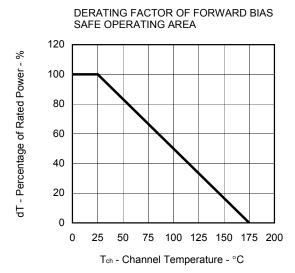
0

0 25

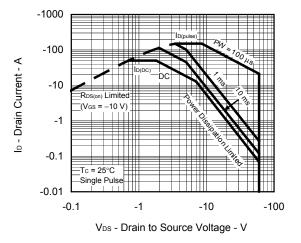
50

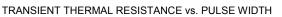
 P_{T} - Total Power Dissipation - W

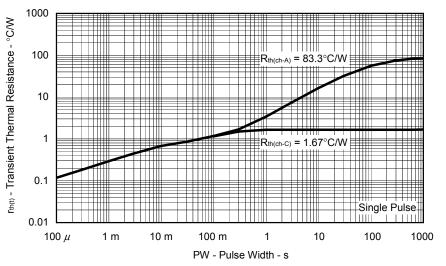
TYPICAL CHARACTERISTICS (T_A = 25°C)





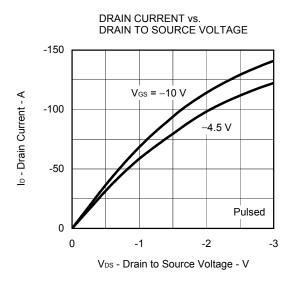


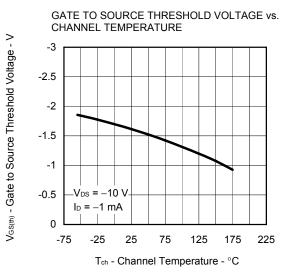




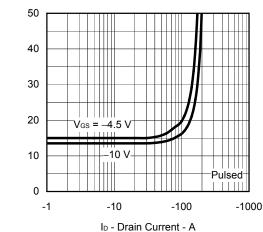
Data Sheet D18689EJ3V0DS



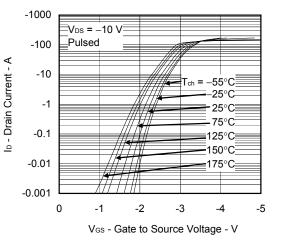




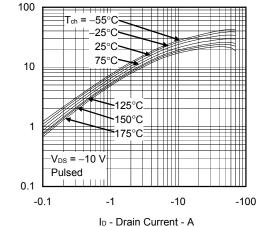
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



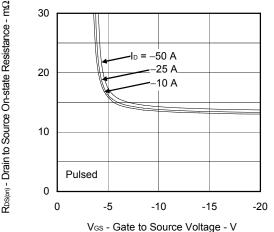




FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



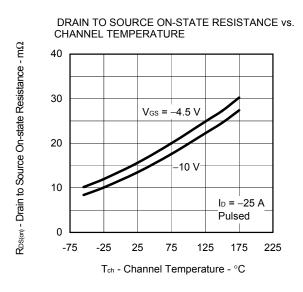
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



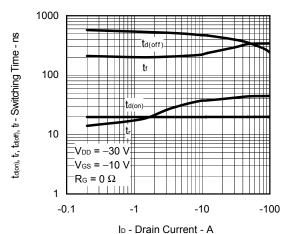
I_D - Drain Current -

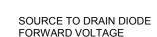
| y_{fs} | - Forward Transfer Admittance - S

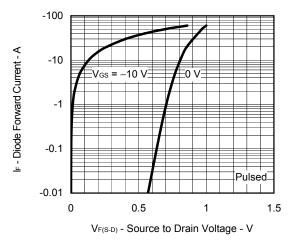
 $R_{DS(on)}$ - Drain to Source On-state Resistance - $m\Omega$



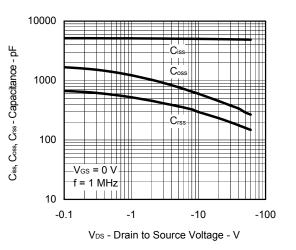
SWITCHING CHARACTERISTICS



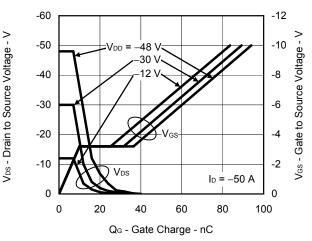




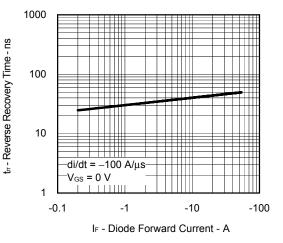
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



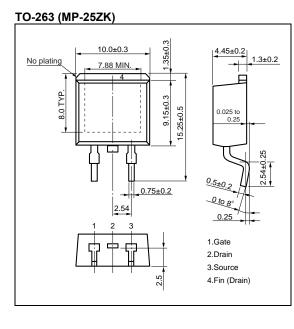
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



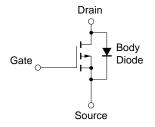
REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT



PACKAGE DRAWING (Unit: mm)



EQUIVALENT CIRCUIT



Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

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